# Single-Frequency High-Power Nanosecond Laser

PULSELAS<sup>™</sup>-A-1064-10W-SF



#### he **PULSELAS™-A-1064-10W-SF**

is a powerful, diode-pumped, singlefrequency, nanosecond laser system which delivers 1 mJ pulse energy at 10 kHz pulse repetition rate. It operates at the fundamental wavelength of 1064 nm. Frequency conversions to 532 nm, 355 nm and 266 nm wavelengths are optional. The distinctive features of this laser like near-transform-limited spectral width, simultaneously high average and peak powers, diffractionlimited output beam, etc. make it an ideal choice for numerous scientific and industrial applications, including optical meteorology, interferometry, high-resolution laser spectroscopy, fiber communications, single pulse holography and many others. The Ethernet connection allows easy access and control of the laser system even in remote, hard-to-reach or hazardous areas.

### Features

- Single frequency (single longitudinal mode)
- High-energy nanosecond pulses
- < 40 MHz spectral width
- Nearly bandwidth transform-limited pulses
- 1 mJ pulse energy at 1064 nm wavelength
- 10 W average power at 1064 nm wavelength
- 80 kW peak power at 1064 nm wavelength
- Nearly **diffraction-limited** beam quality
- Optionally available 532, 355 and 266 nm
- Remote control via Ethernet

### **Applications**

- High-Resolution Laser Spectroscopy
- Nonlinear Frequency Conversion
- Fiber Bragg Grating Fabrication
- Optical Meteorology
- Remote Sensing
- Interferometry
- Lithography
- Holography

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	Single-Frequency High-Power Nanosecond Laser: PULSELAS <sup>™</sup> -A-1064-10W-SI
<b>Technical Spec</b>	ifications: Typical Values
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Parameter	Unit	Fundamental	Harmonics (optional)					
Wavelength	nm	1064	532	355	266			
Pulse Energy	mJ	1	0.45	0.25	0.08			
Pulse Width	ns	< 12	10	< 10	< 10			
Peak Power	kW	> 80	> 38	> 25	8			
Average Power	W	10	4.5	2.5	0.8			
Spectral Width	MHz	< 40	< 50	< 50	< 50			
Repetition Rate	kHz	10 <sup>1)</sup>	10 <sup>1)</sup>	10 <sup>1)</sup>	10 <sup>1)</sup>			
Power Stability	% rms	1 <sup>4)</sup>	4	7	8			
Beam Quality, M <sup>2</sup>	nm	< 1.2	< 1.4	< 1.6	< 1.6			
Beam Diameter (1/e <sup>2</sup> )	mm	1.4 (±10%) <sup>2)</sup> Available on request						
Beam Divergence	mrad	1.0 (±10%) Available on request						
Beam Ellipticity	%	> 90 Available on request						
Spatial Beam Profile		TEM <sub>oo</sub>						
Pulse-to-CW Average Power Contrast		1:150 > 1:10.000 on request						
Pulse-to-CW Peak Power Contrast		$1:15 \times 10^{6}$ > 1:10x10 <sup>10</sup> on request						
Polarization (linear)		> 100:1	> 104:1	> 10⁵:1	> 105:1			
CW Single Frequency Monitor		Optional <sup>3)</sup>						
		Dimensions		Weight				
Laser Head		344 x 120 x 600 mm <sup>3</sup>		11 kg				
Laser Diode Driver		483 x 89 x 341 mm <sup>3</sup>		8 kg				
Recirculating Chiller		483 x 132 x 615 mm <sup>3</sup>		14 kg				
GENERAL CHARACTERISTICS								
Power Requirements		100 – 240 V AC						
Power Consumption		max. 600 W						
Operating Temperature R	ange	20 °C – 28 °C						
Laser Head Cooling		Closed loop water chiller						
Typical Warm-Up Time <sup>4)</sup>		< 5 min (95% of typical power)						
Humidity		max. 70%, non-condensing						
Sync Out		TTL						
Remote Control		Ethernet (LAN), RJ-45						

**Note:** <sup>1)</sup> Other repetition rates are available on request.

<sup>2)</sup> Beam expansion is available on request.

<sup>3)</sup> 5 mW CW single frequency free space beam.

<sup>4)</sup> For full power and stability the warm-up time is 30 min.





**I**→▼ 7.84000ns

Pulse form at 1064 nm wavelength: Single shot.



Laser output spectrum: Linear scale. The measured spectral width is instrument-limited.



Long-term stability of laser output power at 1064 nm.

 (ch)
 20.0mVΩ
 M[4.00ns]
 A
 Ch1
 F

 1
 20.40 %
 1
 20.40 %
 1

Pulse form at 1064 nm wavelength: 10<sup>5</sup> pulses.



Laser output spectrum: Logarithmic scale. Side-mode suppression is better than -25 dB.



Beam pointing stability at 1064 nm.



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## Performance of PULSELAS<sup>™</sup>-A-1064-10W-SF: Typical Values



3D and 2D 1064 nm far-field beam profile measured at ~300 mm distance after laser output.







Beam quality measured according to ISO 11146 standard.

 $M_{eff}^{2} = 1.01$ Div<sub>eff</sub> = 1.08 mrad BPP<sub>eff</sub> = 0.338 mrad\*mm Z<sub>0, eff</sub> = 396 mm

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**Rear View** 



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